



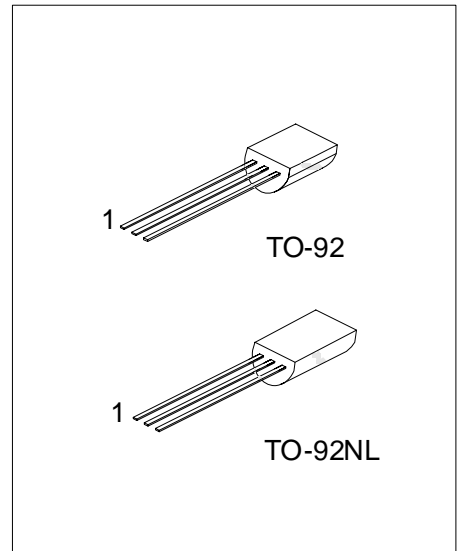
2SD1857

NPN SILICON TRANSISTOR

POWER TRANSISTOR

■ FEATURES

- * High breakdown voltage. ($BV_{CEO}=120V$)
- * Low collector output capacitance. (Typ. 20pF at $V_{CB}=10V$)
- * High transition frequency. ($f_T=80MHz$)



*Pb-free plating product number: 2SD1857L

■ ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
2SD1857-x-T92-B	2SD1857L-x-T92-B	TO-92	E	C	B	Tape Box
2SD1857-x-T92-K	2SD1857L-x-T92-K	TO-92	E	C	B	Bulk
2SD1857-x-T9N-B	2SD1857L-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SD1857-x-T9N-K	2SD1857L-x-T9N-K	TO-92NL	E	C	B	Bulk
2SD1857-x-T9N-R	2SD1857L-x-T9N-R	TO-92NL	E	C	B	Tape Reel

<p>2SD1857L-x-T92-B</p>	<p>(1) B: Tape Box, K: Bulk, R: Tape Reel</p> <p>(2) T92: TO-92, T9N: TO-92NL</p> <p>(3) x: refer to Classification of h_{FE}</p> <p>(4) L: Lead Free Plating, Blank: Pb/Sn</p>
-------------------------	--

■ ABSOLUTE MAXIMUM RATING (Ta=25)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CB0}	120	V
Collector-Emitter Voltage	V _{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Power Dissipation	P _C	1	W
Collector Current	I _C	2	A
Collector Current	I _{CP}	3	A
Junction Temperature	T _J	+150	
Storage Temperature	T _{STG}	-55 ~ +150	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CB0}	I _C =50μA	120			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA	120			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =50μA	5			V
Collector Cut-off Current	I _{CBO}	V _{CB} =100V			1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =4V			1	μA
DC Current Transfer Ratio	h _{FE}	V _{CE} =5V, I _C =0.1A	82		390	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =I _B =1A/0.1A(Note)			0.4	V
Transition Frequency	f _T	V _{CE} =5V, I _E = -0.1A, f=30MHz.		80		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0A, f=1MHz(Note)		20		pF

Note: Measured using pulse current.

■ CLASSIFICATION OF h_{FE}

RANK	P	Q	R
RANGE	82-180	120-270	180-390

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.